

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP628,TLP628-2,TLP628-4

Unit: mm

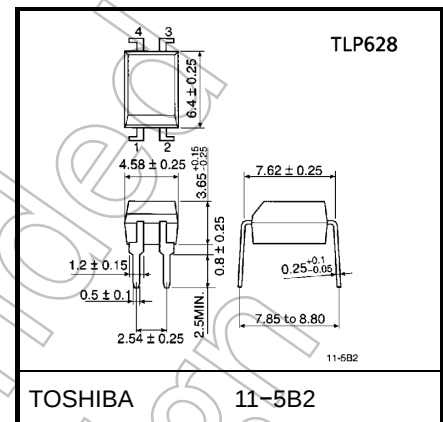
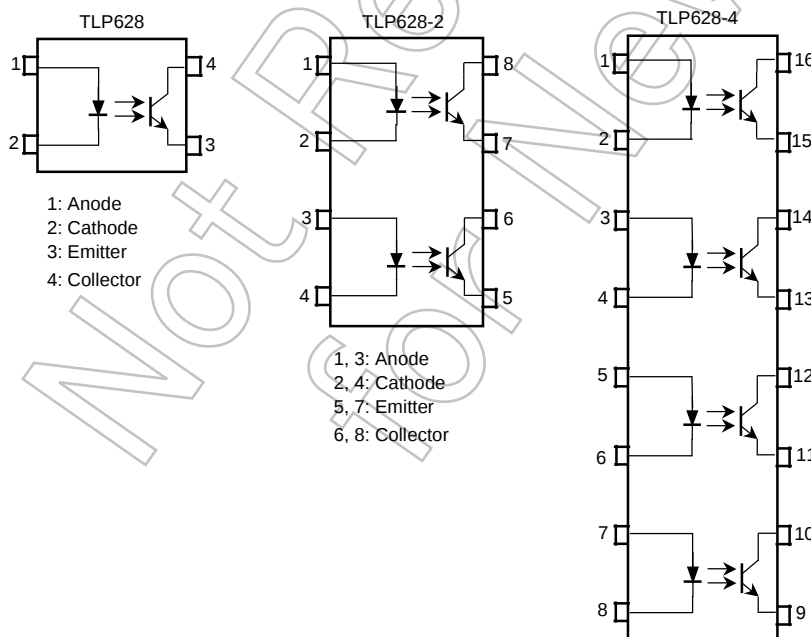
Programmable Controllers
DC-Output Module
Telecommunication

The TOSHIBA TLP628, -2, and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a phototransistor which has a 350V high voltage of collector-emitter breakdown voltage.
The TLP628-2 offers two isolated channels in a eight lead plastic DIP package, while the TLP628-4 provide four isolated channels per package.

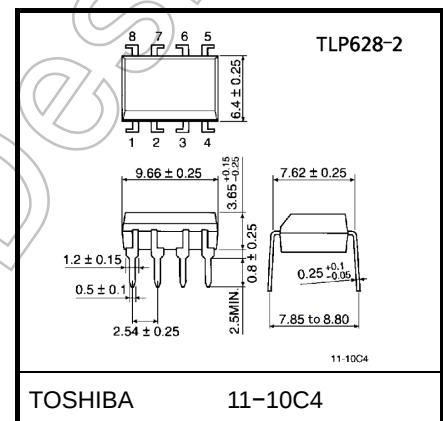
- Collector-emitter voltage: 350 V (min.)
- Current transfer ratio: 50% (min.)
- Isolation voltage: 5000Vrms (min.)
- UL recognized: UL1577, file No. E67349
- cUL approved: CSA Component Acceptance Service No.5A, file No. E67349
- Option (D4) VDE approved : DIN EN60747-5-5 (Note1)

(Note 1) : When a EN60747-5-5 approved type is needed,
please designate "Option(D4)"

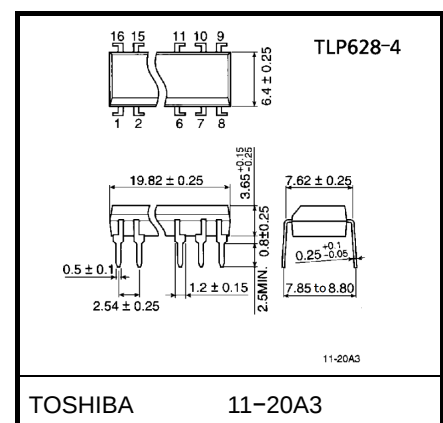
Pin Configurations (top view)



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production
1993/10

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP628	TLP628-2 TLP628-4	
LED	Forward current	I _F	60	50	mA
	Forward current derating	ΔI _F / °C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA / °C
	Pulse forward current	I _{FP}	1 (100μs pulse, 100pps)		A
	Reverse voltage	V _R	5		V
	Input power dissipation	P _D	100	70	mW
	Input power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _D / °C	-1.0	-0.7	mW / °C
Detector	Collector-emitter voltage	V _{CEO}	350		V
	Emitter-collector voltage	V _{ECO}	7		V
	Collector current	I _C	50		mA
	Collector power dissipation (1 circuit)	P _C	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _C / °C	-1.5	-1.0	mW / °C
	Junction temperature	T _j	125		°C
Storage temperature range		T _{stg}	-55 to 125		°C
Operating temperature range		T _{opr}	-55 to 100		°C
Lead soldering temperature		T _{sol}	260 (10s)		°C
Total package power dissipation (1 circuit)		P _T	200	150	mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP _T / °C	-2.0	-1.5	mW / °C
Isolation voltage		BV _S	5000 (AC, 1min., R.H. ≤ 60%) (Note 1)		V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V _{CC}	—	—	200	V
Forward current	I _F	—	16	25	mA
Collector current	I _C	—	—	10	mA
Operating temperature	T _{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR) \text{ CEO}}$	$I_C = 0.1 \text{ mA}$	350	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR) \text{ ECO}}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{\text{CE}} = 300 \text{ V}$	—	10	200	nA
			$V_{\text{CE}} = 300 \text{ V}, T_a = 85^\circ\text{C}$	—	—	50	μA
	Capacitance collector to emitter	C_{CE}	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	$I_F = 5 \text{ mA}, V_{\text{CE}} = 5 \text{ V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = 1 \text{ mA}, V_{\text{CE}} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	$V_{\text{CE}} (\text{sat})$	$I_C = 2.4 \text{ mA}, I_F = 8 \text{ mA}$	—	—	0.4	V
		$I_C = 0.2 \text{ mA}, I_F = 1 \text{ mA}$ Rank GB	—	0.2	—	
			—	—	0.4	

Isolation Characteristics (Ta = 25°C)

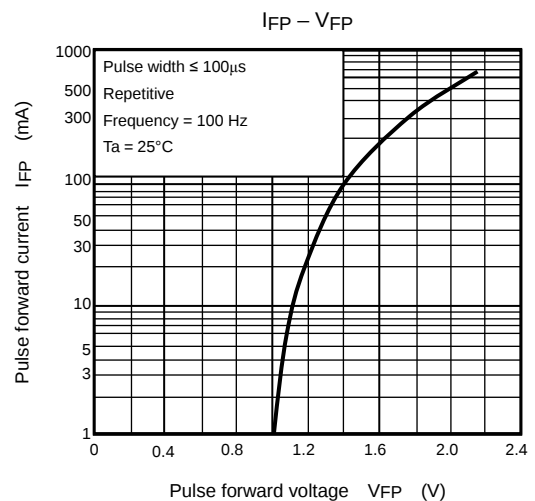
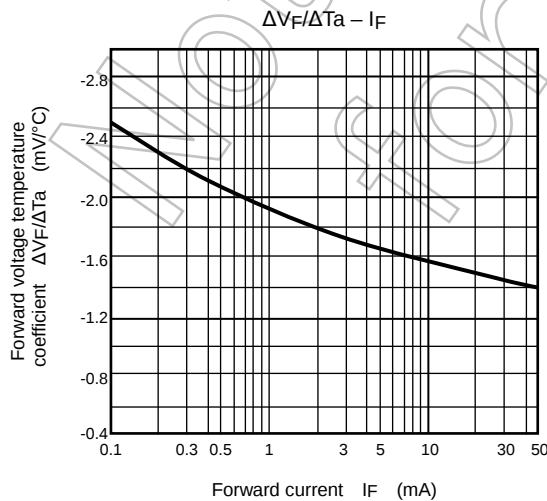
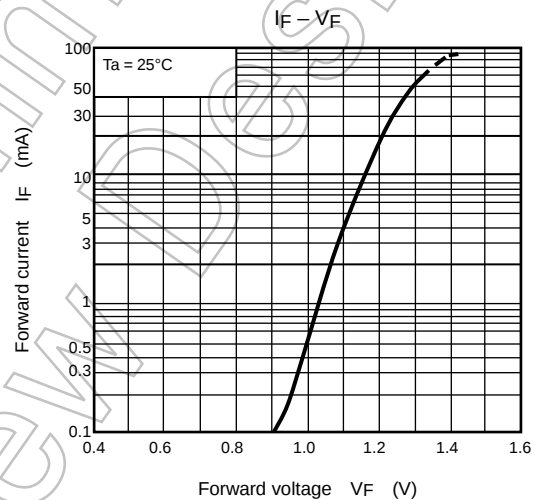
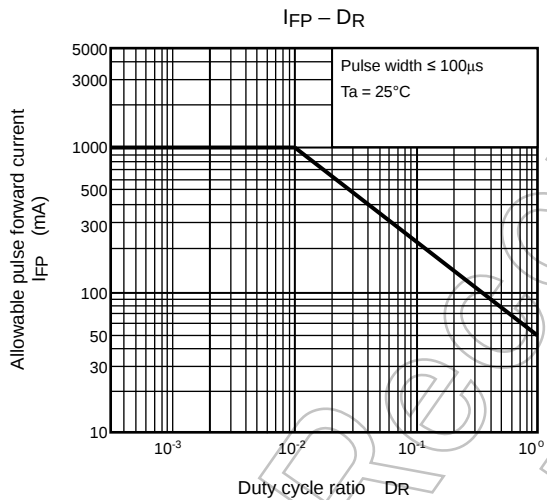
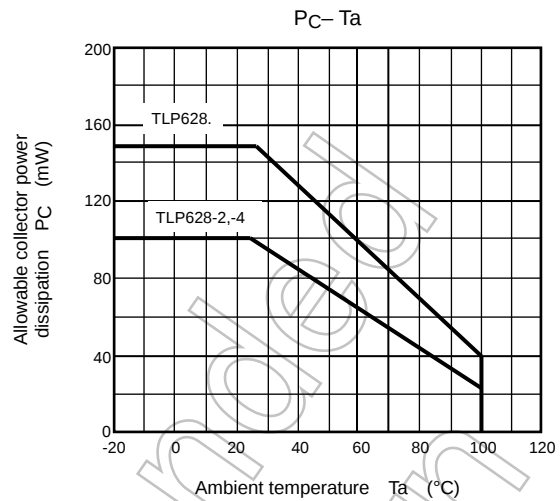
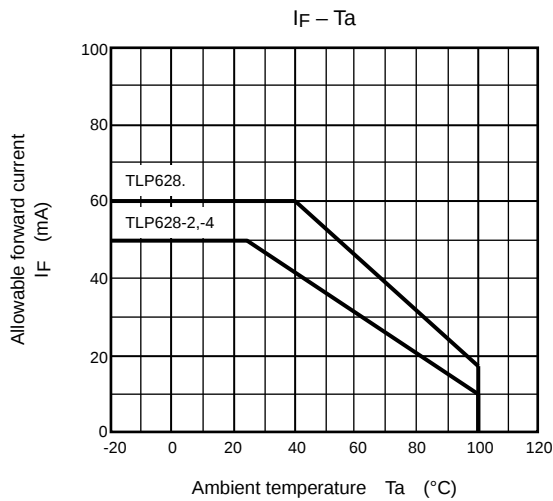
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C_S	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V_{dc}

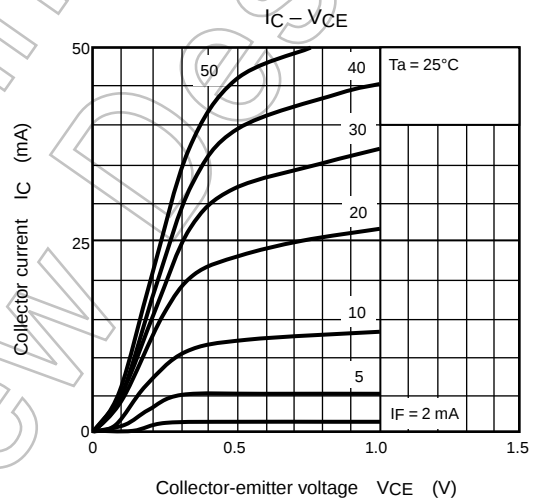
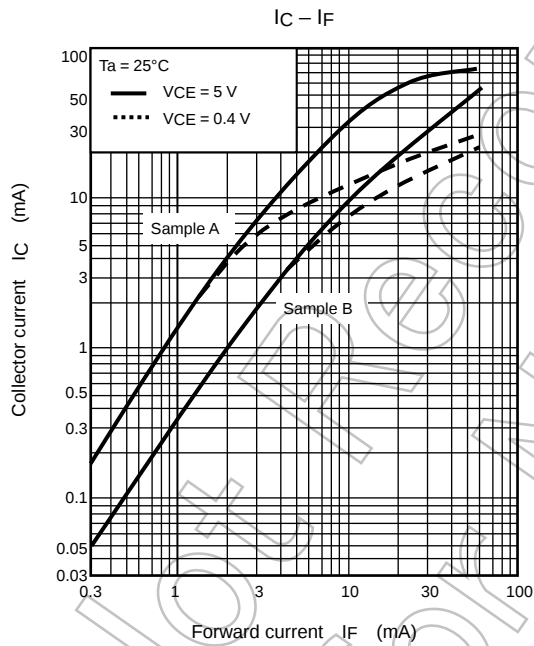
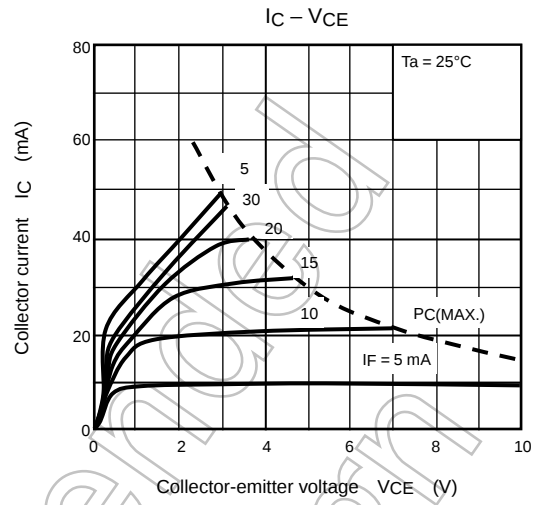
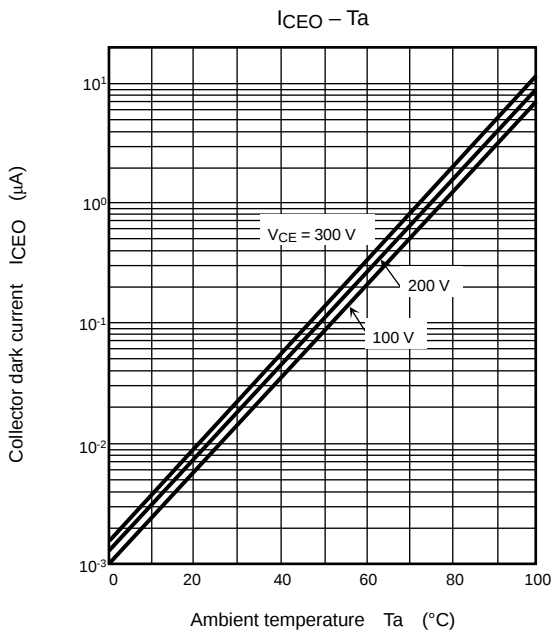
Switching Characteristics (Ta = 25°C)

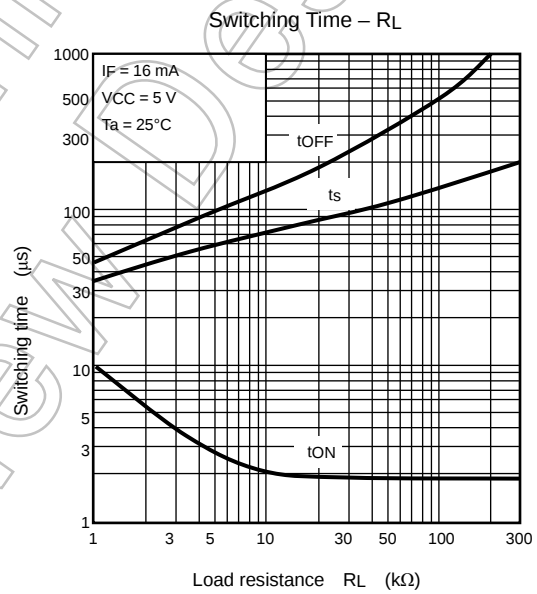
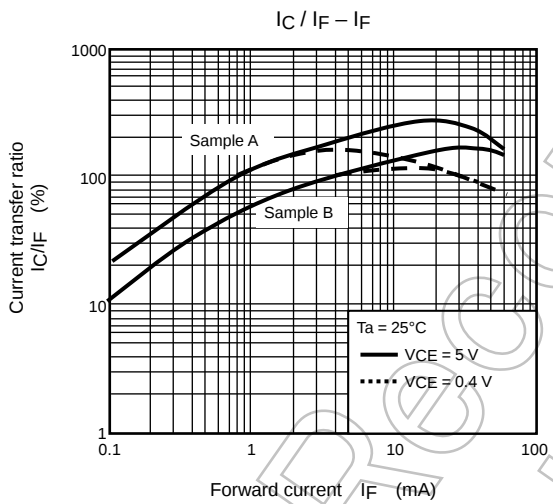
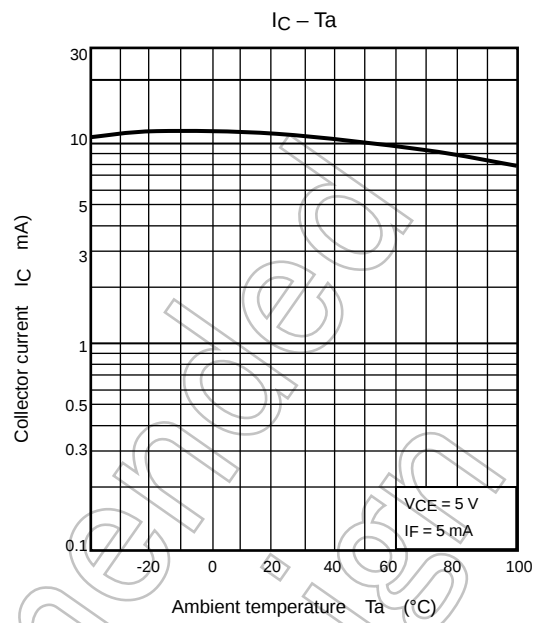
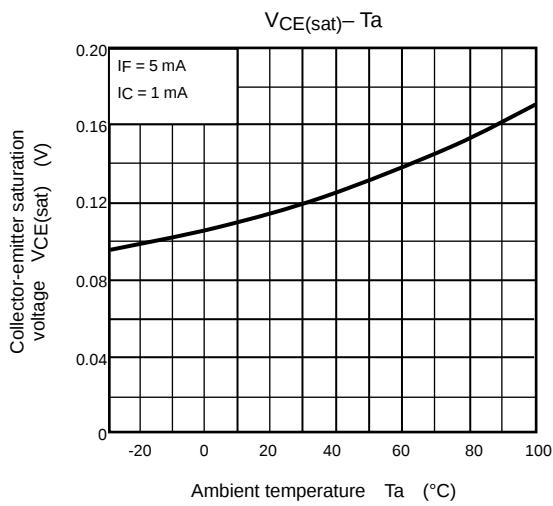
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$ $A_{RL} = 100\Omega$	—	2	—	μs
Fall time	t_f		—	3	—	
Turn-on time	t_{on}		—	3	—	
Turn-off time	t_{off}		—	3	—	
Turn-on time	t_{ON}	$R_L = 1.9\text{ k}\Omega$ (Note 1) $V_{CC} = 5\text{ V}$, $I_F = 16\text{ mA}$	—	3	—	μs
Storage time	t_s		—	40	—	
Turn-off time	t_{OFF}		—	90	—	

Note 1 Switching time test circuit









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